

Charge Protection IC Series with Built-in FET

Standard Protection Type





BD6040GUL, BD6041GUL

No.09031EAT01

Descriptions

The BD6040 GUL, BD6041GUL charger protection IC developed for portable devices provides up to 28V of over voltage protection for charger ICs. Built-in circuits include overvoltage lockout, overcurrent limit, undervoltage protection, internal start up delay, and status flag.

Features

- 1) 28V (max) overvoltage protection
- 2) Low quiescent current (45µA)
- 3) Low Ron (125mΩ) FET
- 4) Overvoltage lockout (OVLO) circuit
- 5) Undervoltage lockout (UVLO) circuit
- 6) Internal 2msec start up delay
- 7) Overcurrent protection circuit
- 8) Compact package: VCSP50L1(1.6mm x 1.6mm, t=0.55mm)

Applications

Mobile phones, MP3 players, Digital Still Camera, PDA, IC recorder, Electronic Dictionary, Handheld Game, Game Controller, Camcorder, Bluetooth Headsets, etc

Line Up

Parameter	Over Voltage Lockout (IN=Increasing)	Over Voltage Lockout (Hysteresis)	Package		
BD6040GUL	6.40V	30mV	VCSP50L1		
BD6041GUL	5.85V	100mV	VCSP50L1		

●Absolute Maximum Ratings (Ta = 25°C)

Contents	Symbol	Rating	Unit	Conditions
Input supply voltage 1	Vmax1	-0.3~30	V	IN1,IN2,IN3,IN4
Input supply voltage 2	Vmax2	-0.3~7	V	other
Power dissipation	Pd	725	mW	
Operating temperature range	Topr	-35~+85	°C	
Storage temperature range	Tstr	-55 ~ +150	°C	

^{%1} When using more than at Ta=25°C, it is reduced 5.8 mW per 1°C.(ROHM specification board 50mmx 58mm mounting.)

●RECOMMENDED OPERATING RANGE (Ta=-35~+85°C))

Parameter	Symbol	Range	Unit	Usage
Input voltage range	V_{in}	2.2~28	V	

^{*} This product is not especially designed to be protected from radioactivity.

●Electrical Characteristics
(Unless otherwise noted, Ta = 25°C, IN=5V)

Deremeter		Davidas	Rating			I Incid	O a sa diti a sa a	
Parameter	Symbol	Device	Min.	Тур.	Max.	Unit	Conditions	
OElectrical								
Input Voltage Range	VIN	BD6040/41	-	-	28	V		
Supply Quiescent Current	ICC	BD6040/41		45	90	μA		
Under Voltage Lockout	UVLO	BD6040/41	2.53	2.65	2.77	V	IN= decreasing	
Under Voltage Lockout Hysteresis	UVLOh	BD6040/41	50	100	150	mV	IN= increasing	
Over Veltage Leekeut	OVLO	BD6040	6.2	6.4	6.6	V	IN= increasing	
Over Voltage Lockout	OVLO	BD6041	5.7	5.85	6.0	V		
Over Veltage Leekeut Livetereeie	0)// 01	BD6040	10	30	50	mV	IN= decreasing	
Over Voltage Lockout Hysteresis	OVLOh	BD6041	50	100	150	mV		
Current limit	ILM	BD6040/41	1.2	-	-	Α		
Vin vs. Vout Res.	RON	BD6040/41	-	125	150	mΩ		
OK Output Low Voltage	OKVO	BD6040/41	-	-	400	mV	SINK=1mA	
OK Leakage Current	OKleak	BD6040/41	-	-	1	μΑ		
EN input voltage (H)	ENH	BD6040/41	1.45	-	-	V		
EN input voltage (L)	ENL	BD6040/41	-	-	0.5	V		
EN input current	ENC	BD6040/41	12	25	50	μΑ	EN=1.5V	
OTimings								
Start Up Delay	Ton	BD6040/41	-	2	4	msec		
OK Going Up Delay	Tok	BD6040/41	-	10	15	msec		
Output Turn Off Time	Toff	BD6040/41	-	2	10	µsec		
Alert Delay	Tovp	BD6040/41	-	1.5	10	µsec		

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● Typical Operating Characteristics

OThe test conditions for the Typical Operating Characteristics are IN=5V, CIN=1uF, COUT=0.1uF, Rok=100kΩ, Ta=25°C, Unless otherwise noted

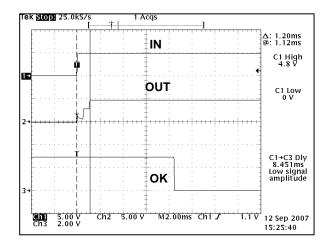


Fig. 1 Start up $(0\rightarrow 5V)$

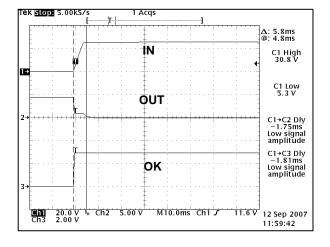


Fig. 3 Input Steps (5→30V)

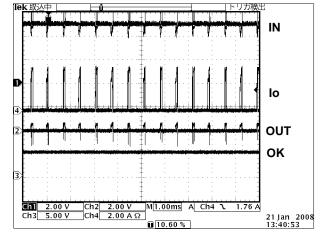


Fig. 5 Output Short Circuit

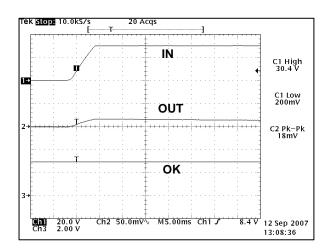


Fig. 2 Input Steps (0→30V)

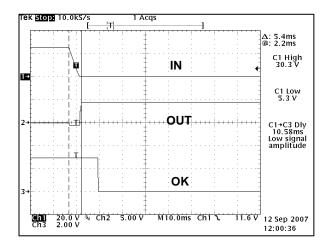


Fig. 4 Input Steps (30→5V)

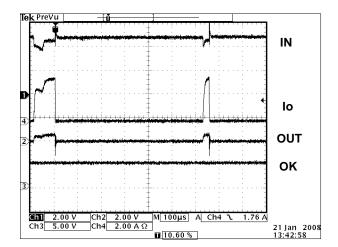


Fig. 6 Output Short Circuit (Zoom)

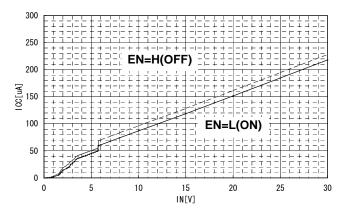


Fig. 7 ICC vs. Input Voltage (0-30V)

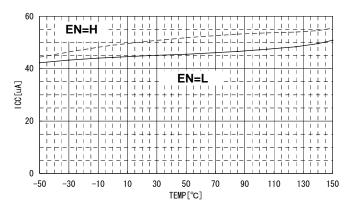


Fig. 9 ICC vs. Temperature (IN=5V)

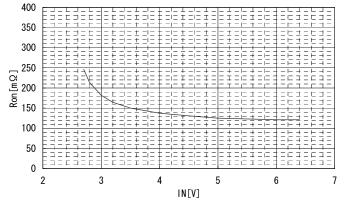


Fig. 11 RON vs. Input Voltage

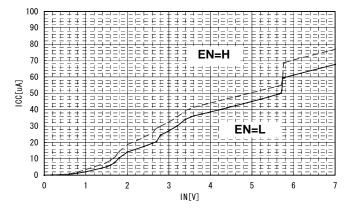


Fig. 8 ICC vs. Input Voltage (0-7V)

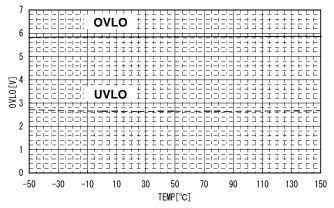


Fig. 10 UVLO/OVLO vs. Temperature

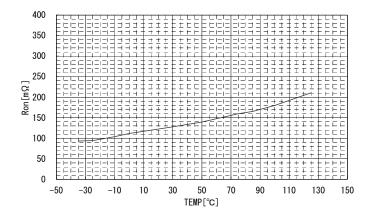


Fig. 12 RON vs. Temperature (IN=5V)

Block Diagram

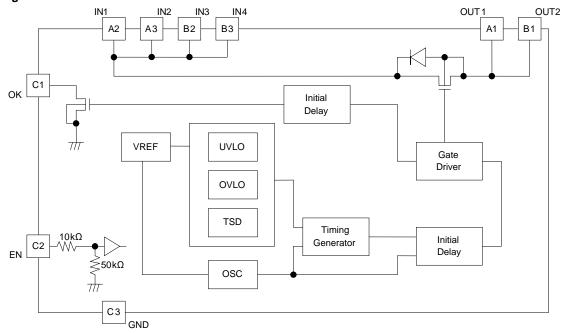
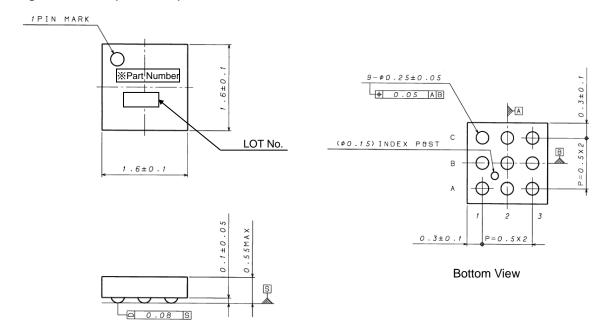


Fig. 13 Block Diagram

● Package Dimensions(VCSP50L1)



 $\ensuremath{\mathsf{XBD6040GUL}}$ is "6040", BD6041GUL is "6041".

Fig. 14 Package Dimensions

●Ball Configuration

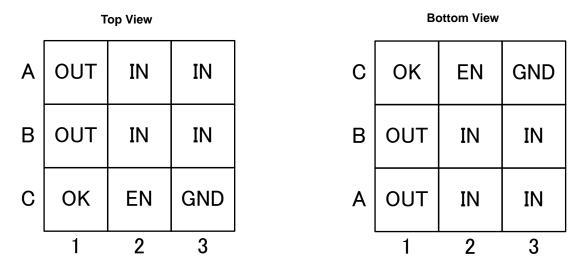
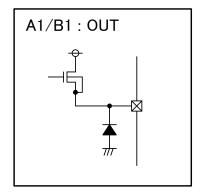


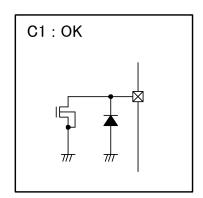
Fig. 15 Ball Configuration

●Pin Descriptions

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No.	Pin	Name	1/0	ESD	Diode	Function			
INO.	FIII	ivallie	1/0	IN	GND	FullCliOH			
1	A2	IN1	I	-	0				
2	А3	IN2	I	-	0	Bypass with 1uF Ceramic capacitor or larger to get full 15KV ESD			
3	B2	IN3	I	-	0	protection (Air, IEC61000-4-2) at the input			
4	В3	IN4	I	-	0				
5	A1	OUT1	0	-	0	Output Voltage Din			
6	B1	OUT2	0	-	0	Output Voltage Pin			
7	C3	GND	-	0	-	Ground Pin			
8	C1	OK	0	-	0	Active-low open drain output to signal if the adapter voltage is correct			
9	C2	EN	I	-	0	Enable input Drive EN high to turn off OUT (Hi-z output)			

●Equivalent Circuit





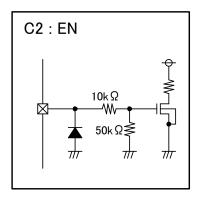


Fig. 16 Block Diagram

● Typical Application Circuit

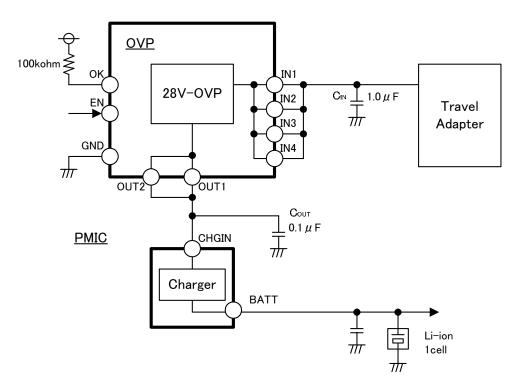


Fig. 17 Application Circuit

- · Safety is high because it detects, and it protects it for an abnormal voltage up to 28V.
- It contributes to the miniaturization because all external is built into.

●Timing Diagram

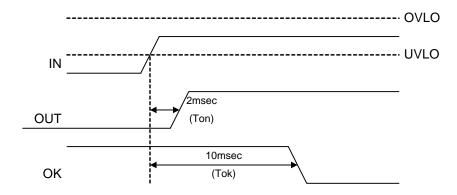


Fig. 18 Start up sequence

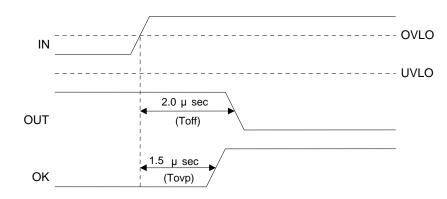


Fig. 19 Shutdown by over voltage detection

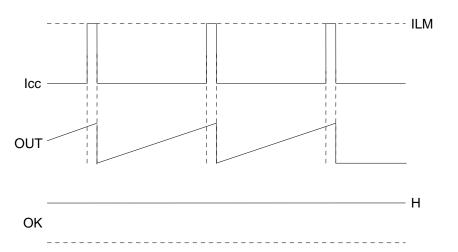
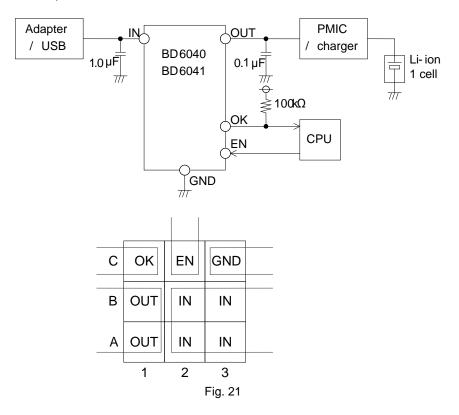


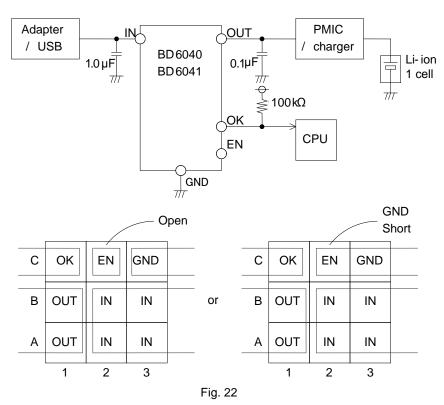
Fig. 20 Operation by current limit detection

● Examples of Application Circuit (Ball Configuration is BOTTOM VIEW)

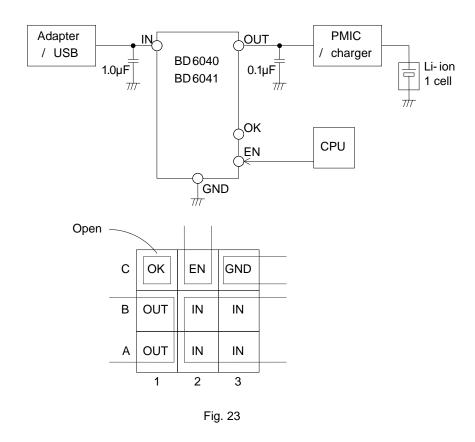
A: In case of both EN & OK pins are connected.



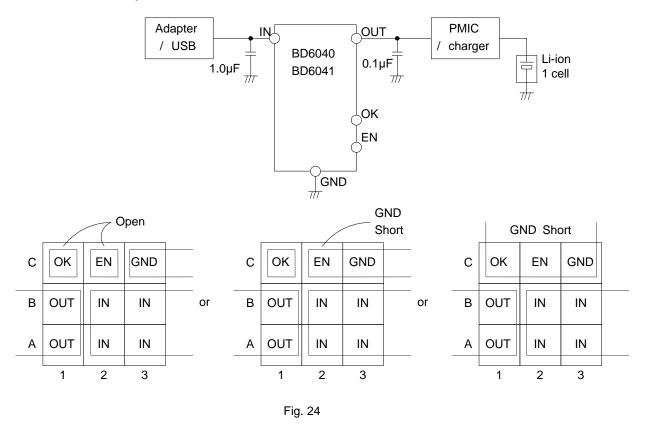
B: In case of OK pin is connected.



C: In case of EN pin is connected.



D: In case of both EN & OK pins are not connected.



Notes foer use

(1) Absolute maximum ratings

If applied voltage (VDD, VIN), operating temperature range (Topr), or other absolute maximum ratings are exceeded, there is a risk of damage. Since it is not possible to identify short, open, or other damage modes, if special modes in which absolute maximum ratings are exceeded are assumed, consider applying fuses or other physical safety measures.

(2) Recommended operating range

This is the range within which it is possible to obtain roughly the expected characteristics. For electrical characteristics, it is those that are guaranteed under the conditions for each parameter. Even when these are within the recommended operating range, voltage and temperature characteristics are indicated.

(3) Reverse connection of power supply connector

There is a risk of damaging the LSI by reverse connection of the power supply connector. For protection from reverse connection, take measures such as externally placing a diode between the power supply and the power supply pin of the LSI.

(4) Power supply lines

In the design of the board pattern, make power supply and GND line wiring low impedance.

When doing so, although the digital power supply and analog power supply are the same potential, separate the digital power supply pattern and analog power supply pattern to deter digital noise from entering the analog power supply due to the common impedance of the wiring patterns. Similarly take pattern design into account for GND lines as well. Furthermore, for all power supply pins of the LSI, in conjunction with inserting capacitors between power supply and GND pins, when using electrolytic capacitors, determine constants upon adequately confirming that capacitance loss occurring at low temperatures is not a problem for various characteristics of the capacitors used.

(5) GND voltage

Make the potential of a GND pin such that it will be the lowest potential even if operating below that. In addition, confirm that there are no pins for which the potential becomes less than a GND by actually including transition phenomena.

(6) Shorts between pins and misinstallation

When installing in the set board, pay adequate attention to orientation and placement discrepancies of the LSI. If it is installed erroneously, there is a risk of LSI damage. There also is a risk of damage if it is shorted by a foreign substance getting between pins or between a pin and a power supply or GND.

(7) Operation in strong magnetic fields

Be careful when using the LSI in a strong magnetic field, since it may malfunction.

(8) Inspection in set board

When inspecting the LSI in the set board, since there is a risk of stress to the LSI when capacitors are connected to low impedance LSI pins, be sure to discharge for each process. Moreover, when getting it on and off of a jig in the inspection process, always connect it after turning off the power supply, perform the inspection, and remove it after turning off the power supply. Furthermore, as countermeasures against static electricity, use grounding in the assembly process and take appropriate care in transport and storage.

(9) Input pins

Parasitic elements inevitably are formed on an LSI structure due to potential relationships. Because parasitic elements operate, they give rise to interference with circuit operation and may be the cause of malfunctions as well as damage. Accordingly, take care not to apply a lower voltage than GND to an input pin or use the LSI in other ways such that parasitic elements operate. Moreover, do not apply a voltage to an input pin when the power supply voltage is not being applied to the LSI. Furthermore, when the power supply voltage is being applied, make each input pin a voltage less than the power supply voltage as well as within the guaranteed values of electrical characteristics.

(10) Ground wiring pattern

When there is a small signal GND and a large current GND, it is recommended that you separate the large current GND pattern and small signal GND pattern and provide single point grounding at the reference point of the set so that voltage variation due to resistance components of the pattern wiring and large currents do not cause the small signal GND voltage to change. Take care that the GND wiring pattern of externally attached components also does not change.

(11) Externally attached capacitors

When using ceramic capacitors for externally attached capacitors, determine constants upon taking into account a lowering of the rated capacitance due to DC bias and capacitance change due to factors such as temperature.

(12) Thermal shutdown circuit (TSD)

When junction temperatures become 170°C (typ) or higher, the thermal shutdown circuit operates and turns a switch OFF. The thermal shutdown circuit, which is aimed at isolating the LSI from thermal runaway as much as possible, is not aimed at the protection or guarantee of the LSI. Therefore, do not continuously use the LSI with this circuit operating or use the LSI assuming its operation.

(13) Thermal design

Perform thermal design in which there are adequate margins by taking into account the permissible dissipation (Pd) in actual states of use.

Power Dissipation

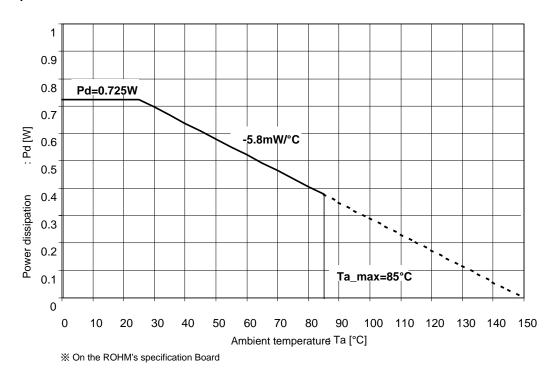
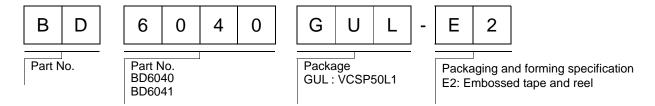
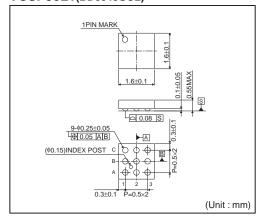


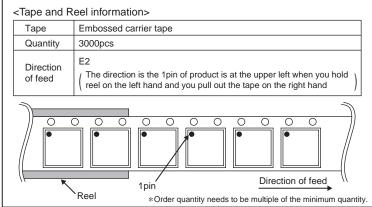
Fig. 25 Power dissipation vs. Ta

Ordering part number

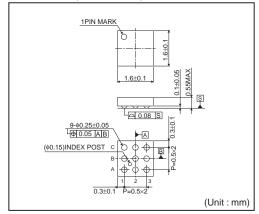


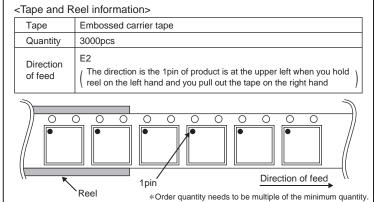
VCSP50L1(BD6040GUL)





VCSP50L1(BD6041GUL)





Notes

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